TOSHIBA Photocoupler Photorelay

TLP4192G

Telecommunication Measurement Equipment Security Equipment FA

The Toshiba TLP4192G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP package. This 1-form-B (NC) photorelay features a withstanding voltage of $350~\rm V$.

• 6-pin SOP (2.54SOP6): Height = 2.1 mm, pitch = 2.54 mm

• Normally closed (1-form-B) device

• Peak off-state voltage: 350 V (min)

• Trigger LED current: 3 mA (max)

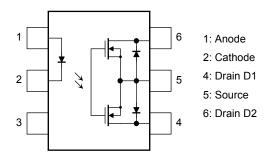
• On-state current: 90 mA (max)

• On-state resistance: 50Ω (max)

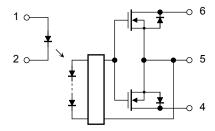
• Isolation voltage: 1500 Vrms (min)

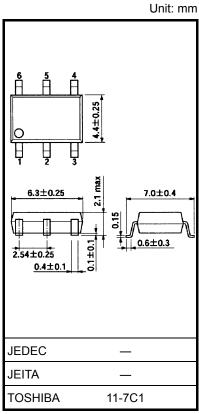
• UL Recognized: UL1577, File No. E67349

Pin Configuration (top view)



Schematic





Weight: 0.13 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

	Characteristics	Symbol	Rating	Unit		
	Forward current	lF	50	mA		
	Forward current derating (Ta	≧ 25°C)	ΔI _F /°C	-0.5	mA/°C	
딬	Peak forward current (100 μs	pulse, 100 pps)	IFP	1	Α	
_	Reverse voltage		V _R	5	V	
	Junction temperature	Tj	125	°C		
	Off-state output terminal volta	age	V _{OFF}	350	V	
	On-state current	A connection		90	mA	
		B connection	I _{ON}	90		
ctor		C connection		180		
Detector	On-state current derating (Ta ≧ 25°C)	A connection		-0.9		
		B connection	Δl _{ON} /°C	-0.9	mA/°C	
	(=20 0)	C connection		-1.8		
	Junction temperature		Tj	125	°C	
Storage temperature range			T _{stg} –55 to 125		°C	
Operating temperature range			T _{opr}	T _{opr} -40 to 85		
Lead	soldering temperature (10 s)	T _{sol}	260	°C		
Isola	tion voltage (AC, 1 min, R.H.	≦ 60%) (Note 1)	BVS	1500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

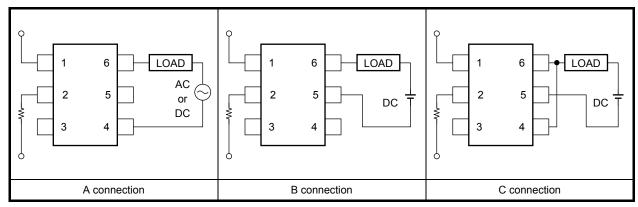
Note 1: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	280	V
Forward current	ΙF	5	_	25	mA
On-state current	I _{ON}	_	_	90	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Circuit Connections



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Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 350 V, I _F = 5 mA	_	_	1	μΑ
Dete	Capacitance	C _{OFF}	V = 0, f = 1 MHz, I _F = 5 mA	_	30	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I _{FC}	I _{OFF} = 10 μA	_	1	3	mA
Return LED current		I _{FT}	I _{ON} = 90 mA	0.1	_	_	mA
	A connection		I _{ON} = 90 mA	_	27	50	
On-state resistance	B connection	R _{ON}	I _{ON} = 90 mA	_	20	43	Ω
	C connection		I _{ON} = 180 mA	_	10	_	

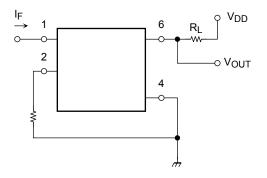
Isolation Characteristics (Ta = 25°C)

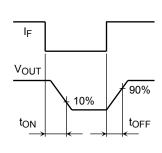
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5×10^{10}	10 ¹⁴	_	Ω
	BVS	AC, 1 min	1500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	3000	_	VIIIIS
		DC, 1 min, in oil	_	3000	_	Vdc

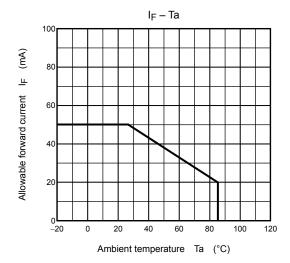
Switching Characteristics (Ta = 25°C)

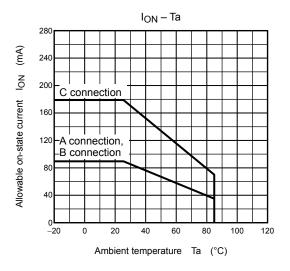
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$	_	0.25	0.5	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 2)		0.5	1	ms

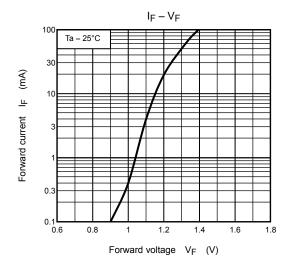
Note 2: Switching time test circuit

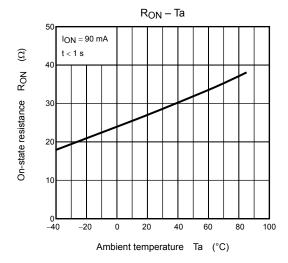


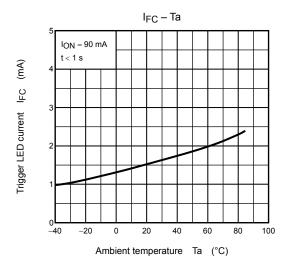


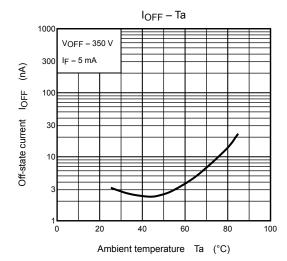


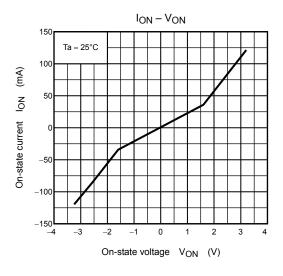


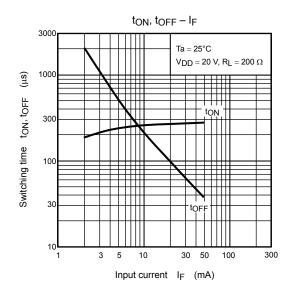


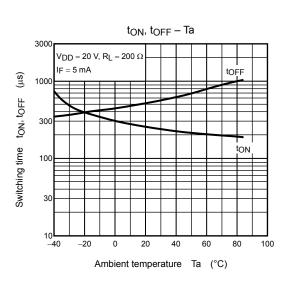












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